

TC58BYG0S3HBAI6

TC58BYG0S3HBAI6 Information



For Reference Only

Part Number TC58BYG0S3HBAI6

Manufacturer Toshiba Semiconductor and Storage

Category Integrated Circuits (ICs)

Memory

Description IC EEPROM 1GBIT 25NS 67VFBGA

Package 67-VFBGA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









TC58BYG0S3HBAI6 Specifications

Manufacturer Part Number	TC58BYG0S3HBAI6
Manufacturer	Toshiba Semiconductor and Storage
Category	Integrated Circuits (ICs)
	Memory
Package	67-VFBGA
Series	Benand?
Memory Type	Non-Volatile
Memory Format	EEPROM
Technology	EEPROM - NAND
Memory Size	1Gb (128M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	25ns
Access Time	25ns
Voltage - Supply	1.7 V ~ 1.95 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	67-VFBGA
Supplier Device Package	67-VFBGA (6.5x8)
	Report errors?

TC58BYG0S3HBAI6 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TC58BYG0S3HBAI6 Payment Methods



















TC58BYG0S3HBAI6 Shipping Methods













If you have any question about TC58BYG0S3HBAI6, please do not hesitate to contact us!

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